

SILICON POWER MOS FET NE5500179A

4.8 V OPERATION SILICON RF POWER LD-MOS FET FOR 1.9 GHz 1 W TRANSMISSION AMPLIFIERS

DESCRIPTION

The NE5500179A is an N-channel silicon power MOS FET specially designed as the transmission driver amplifier for 4.8 V GSM 1 800 and GSM 1 900 handsets. Dies are manufactured using NEC's NEWMOS technology (NEC's 0.6 μ m WSi gate lateral-diffusion MOS FET) and housed in a surface mount package. The device can deliver 30.0 dBm output power with 55% power added efficiency at 1.9 GHz under the 4.8 V supply voltage, or can deliver 27 dBm output power with 50% power added efficiency at 3.5 V, respectively.

FEATURES

•	High output power	: $P_{out} = 30.0 \text{ dBm TYP}$. (VDS = 4.8 V, IDSet = 200 mA, f = 1.9 GHz, Pin = 20 dBm)
٠	High power added efficiency	: η_{add} = 55% TYP. (VDs = 4.8 V, IDset = 200 mA, f = 1.9 GHz, Pin = 20 dBm)
٠	High linear gain	: G_L = 14.0 dB TYP. (VDs = 4.8 V, IDset = 200 mA, f = 1.9 GHz, Pin = 10 dBm)
٠	Surface mount package	: 5.7 \times 5.7 \times 1.1 mm MAX.
•	Single supply	: Vbs = 3.0 to 6.0 V

APPLICATIONS

- Digital cellular phones : 4.8 V driver amplifier for GSM 1 800/ GSM 1 900 class 1 handsets, or 4.8 V final stage amplifier
- Digital cordless phones : 3.5 V final stage amplifier for DECT
- Others : General purpose amplifiers for 1.6 to 2.5 GHz TDMA applications

ORDERING INFORMATION

Part Number	Package	Marking	Supplying Form
NE5500179A-T1	79A	R1	12 mm wide embossed tapingGate pin face the perforation side of the tapeQty 1 kpcs/reel

Remark To order evaluation samples, consult your NEC sales representative. Part number for sample order: NE5500179A

Caution Please handle this device at static-free workstation, because this is an electrostatic sensitive device.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version. Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

ABSOLUTE MAXIMUM RATINGS (TA = +25°C)

Parameter	Symbol	Ratings	Unit
Drain to Source Voltage	Vds	8.5	V
Gate to Source Voltage	Vgso	5.0	V
Drain Current	lo	0.25	А
Drain Current (Pulse Test)	ID ^{Note}	0.5	А
Total Power Dissipation	Ptot	1.6	W
Channel Temperature	Tch	125	°C
Storage Temperature	Tstg	-65 to +125	°C

Note Duty Cycle \leq 50%, Ton \leq 1 ms

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Drain to Source Voltage	Vds		3.0	4.8	6.0	V
Gate to Source Voltage	Vgso		0	2.0	3.5	V
Drain Current (Pulse Test)	lь	Duty Cycle \leq 50%, T _{on} \leq 1 ms	-	340	_	mA
Input Power	Pin	f = 1.9 GHz, V _{DS} = 4.8 V	0	20	22	dBm

ELECTRICAL CHARACTERISTICS (TA = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
Gate to Source Leak Current	lgso	Vgss = 5.0 V	-	_	100	nA
Saturated Drain Current (Zero Gate Voltage Drain Current)	loss	V _{DSS} = 8.5 V	_	-	100	nA
Gate Threshold Voltage	Vth	V _{DS} = 4.8 V, I _{DS} = 1 mA	1.0	1.45	2.0	V
Transconductance	g m	Vps = 4.8 V, lps = 250 mA	-	420	-	mS
Drain to Source Breakdown Voltage	BV _{DS}	Ibss = 10 μ A	20	24	_	V
Thermal Resistance	Rth	Channel to Case	-	10	-	°C/W
Linear Gain	G∟	f = 1.9 GHz, P _{in} = 10 dBm, V _{DS} = 4.8 V, I _{Dset} = 200 mA, Note 1, 2	-	14.0	-	dB
Output Power	Pout	f = 1.9 GHz, P _{in} = 20 dBm,	28.5	30.0	-	dBm
Operating Current	Гор	V _{DS} = 4.8 V, I _{Dset} = 200 mA, Note 1, 2	-	340	-	mA
Power Added Efficiency	η add		48	55	_	%

Notes 1. Peak measurement at Duty Cycle \leq 50%, Ton \leq 1 ms.

2. DC performance is 100% testing. RF performance is testing several samples per wafer. Wafer rejection criteria for standard devices is 1 reject for several samples.

2.5

3.0

30

20

3.0

25



TYPICAL CHARACTERISTICS ($T_A = +25^{\circ}C$)

Preliminary Data Sheet P15190EJ1V0DS

4.0





Input Power Pin (dBm)

Preliminary Data Sheet P15190EJ1V0DS

Input Power Pin (dBm)



Remark The graphs indicate nominal characteristics.

S-PARAMETERS

Test Conditions: VDs = 4.8 V, IDset = 100 mA

Frequency	S	5 11		S ₂₁			S 12		S	5 22		MSG Note	к
GHz	MAG.	ANG.	dB	MAG.	ANG.	dB	MAG.	ANG.	MAG.	ANG.	dB	dB	
0.1	0.844	-69.6	25.2	18.11	135.5	-28.5	0.037	48.2	0.517	-85.0		26.8	0.00
0.2	0.792	-107.8	21.7	12.12	112.3	-26.1	0.049	23.2	0.569	-120.7		23.9	0.06
0.3	0.757	-127.4	18.7	8.58	98.8	-25.5	0.052	10.8	0.598	-136.5		22.1	0.08
0.4	0.747	-138.7	16.4	6.58	89.4	-25.7	0.052	3.3	0.618	-144.8		21.0	0.11
0.5	0.746	-146.2	14.5	5.28	82.1	-25.7	0.052	-4.1	0.641	-149.5		20.1	0.13
0.6	0.751	-151.8	12.7	4.32	76.2	-26.0	0.050	-8.9	0.660	-153.4		19.3	0.18
0.7	0.756	-155.6	11.3	3.68	70.9	-26.3	0.048	-12.6	0.681	-156.2		18.8	0.22
0.8	0.772	-159.5	9.9	3.12	65.9	-26.4	0.048	-17.0	0.696	-158.9		18.1	0.23
0.9	0.777	-162.3	8.8	2.75	61.3	-26.9	0.045	-22.1	0.715	-161.0		17.9	0.28
1.0	0.785	-165.0	7.6	2.40	58.2	-27.2	0.043	-21.9	0.732	-162.9		17.4	0.33
1.1	0.796	-167.7	6.7	2.17	53.7	-27.8	0.040	-26.9	0.749	-164.9		17.2	0.35
1.2	0.804	-169.9	5.7	1.91	51.4	-28.3	0.038	-29.2	0.763	-166.9		17.0	0.42
1.3	0.814	-172.4	4.8	1.74	46.4	-28.7	0.036	-30.5	0.776	-169.1		16.8	0.45
1.4	0.820	-174.6	4.0	1.58	44.3	-29.0	0.035	-31.4	0.789	-171.0		16.5	0.48
1.5	0.827	-176.8	3.2	1.45	39.7	-28.9	0.035	-36.6	0.803	-172.7		16.1	0.44
1.6	0.832	-179.6	2.5	1.33	38.4	-30.0	0.031	-38.5	0.808	-175.0		16.3	0.62
1.7	0.833	177.9	1.5	1.19	34.6	-30.5	0.030	-38.3	0.814	-176.7		16.0	0.78
1.8	0.846	175.6	1.1	1.13	31.6	-31.0	0.028	-38.7	0.829	-179.2		16.1	0.70
1.9	0.843	172.9	0.2	1.02	28.3	-31.8	0.025	-38.1	0.834	178.7		16.0	0.98
2.0	0.850	170.3	0.0	0.99	27.1	-32.2	0.024	-40.9	0.840	176.5		16.1	0.97
2.1	0.851	167.1	-1.0	0.89	23.3	-33.5	0.021	-42.9	0.842	174.4	12.4		1.42
2.2	0.854	165.1	-1.6	0.83	21.4	-34.1	0.019	-48.0	0.847	172.1	11.7		1.62
2.3	0.861	162.3	-2.4	0.75	16.9	-35.1	0.017	-43.6	0.856	169.1	10.9		1.88
2.4	0.857	159.5	-2.3	0.76	15.5	-34.9	0.017	-40.8	0.866	167.0	11.5		1.68
2.5	0.870	156.6	-3.4	0.67	13.8	-36.1	0.015	-49.0	0.862	164.7	10.2		2.20
2.6	0.870	153.9	-3.6	0.65	12.0	-35.8	0.016	-36.8	0.865	162.0	10.1		2.13
2.7	0.867	151.6	-5.0	0.56	9.0	-39.4	0.010	-33.0	0.866	159.1	7.8		4.44
2.8	0.870	148.9	-4.8	0.57	3.9	-39.9	0.010	-43.4	0.879	156.7	8.6		3.96
2.9	0.873	146.5	-5.6	0.52	4.7	-42.4	0.007	-18.3	0.879	154.5	7.6		6.01
3.0	0.882	143.9	-5.7	0.51	2.7	-41.3	0.008	-15.0	0.885	152.0	8.2		4.60

Note When $K \ge 1$, the MAG (Maximum Available Gain) is used.

When K < 1, the MSG (Maximum Stable Gain) is used.

$$MAG = \left| \frac{S_{21}}{S_{12}} \right| (K - \sqrt{(K^2 - 1)})$$
$$MSG = \left| \frac{S_{21}}{S_{12}} \right|, K = \frac{1 + |\Delta|^2 - |S_{11}|^2 - |S_{22}|^2}{2 \cdot |S_{12}| \cdot |S_{21}|},$$
$$\Delta = S_{11} \cdot S_{22} - S_{21} \cdot S_{12}$$

LARGE SIGNAL IMPEDANCE (VDS = 4.8 V, IDset = 100 mA, Pin = 20 dBm)

f (GHz)	$Z_{in}\left(\Omega ight)$	$Z_OL\left(\Omega ight)^{Note}$		
1.9	TBD	TBD		

Note ZoL is the conjugate of optimum load impedance at given voltage, idling current, input power and frequency.

PACKAGE DIMENSIONS

79A (UNIT: mm)



79A PACKAGE RECOMMENDED P.C.B. LAYOUT (UNIT: mm)



RECOMMENDED SOLDERING CONDITIONS

This product should be soldered and mounted under the following recommended conditions. For soldering methods and conditions other than those recommended below, contact your NEC sales representative.

Soldering Method	Soldering Conditions	Recommended Condition Symbol
Infrared Reflow	Package peak temperature: 235°C or below, Time: 30 seconds or less (at 210°C or higher), Count: 2 times or less, Exposure: limit: None ^{Note}	IR35-00-2
Partial Heating	Pin temperature: 260°C or below, Time: 5 seconds or less (per pin row) Exposure: limit: None ^{№00}	_

Note After opening the dry pack, store it at 25°C or less and 65% RH or less for the allowable storage period.

Caution Do not use different soldering methods together (except for partial heating).

[MEMO]

[MEMO]

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